

Cascadable Amplifier 100 to 2000 MHz

Rev. V4

Features

LOW NOISE FIGURE: 3.5 dB (TYP.)
HIGH THIRD ORDER IP: +32 dBm (TYP.)

• HIGH OUTPUT LEVEL: +21 dBm (TYP.)

LOW VSWR: 1.8:1 (TYP.)

Description

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The A32 RF amplifier is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

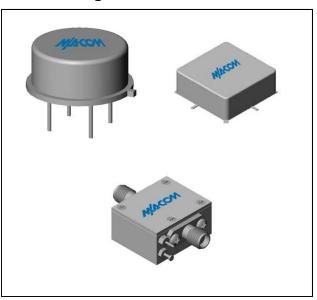
This single stage GaAs FET feedback amplifier design displays impressive performance characteristics over a broadband frequency range. An RF choke is used for DC power supply decoupling.

Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available.

Ordering Information

Part Number	Package		
A32	TO-8		
SMA32	Surface Mount		
CA32	SMA Connectorized		

Product Image



Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +15 V_{DC}$

Parameter	Units	Typical	Guaranteed	
		25°C	0º to 50ºC	-54º to +85ºC*
Frequency	MHz	10-2000	10-2000	10-2000
Small Signal Gain (min)	dB	10.0	9.0	8.5
Gain Flatness (max)	dB	±3.0	±0.7	±1.0
Reverse Isolation	dB	20		
Noise Figure (max)	dB	3.5	4.0	4.5
Power Output @ 1 dB comp. (min)	dBm	21.0	19.0	18.0
IP3	dBm	+32		
IP2	dBm	+38		
Second Order Harmonic IP	dBm	+40		
VSWR Input / Output (max)		1.8:1 / 1.8:1	2.1:1 / 2.1:1	2.3:1 / 2.3:1
DC Current @ 15 Volts (max)	mA	94	98	100

Absolute Maximum Ratings

Parameter	Absolute Maximum	
Storage Temperature	-62°C to +125°C	
Case Temperature	+125°C	
DC Voltage	+17 V	
Continuous Input Power	13 dBm	
Short Term Input power (1 minute max.)	50 mW	
Peak Power (3 µsec max.)	0.5 W	
"S" Series Burn-In Temperature (case)	+125°C	

Thermal Data: $V_{CC} = +15 V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	182°C/W
Transistor Power Dissipation P _d	0.288 W
Junction Temperature Rise Above Case T _{jc}	+52°C

 $^{^{\}star}$ Over temperature performance limits for part number CA32, guaranteed from 0°C to +50°C only.

Commitment to produce in volume is not guaranteed.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

[•] North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400

India Tel: +91.80.4155721
 China Tel: +86.21.2407.1588
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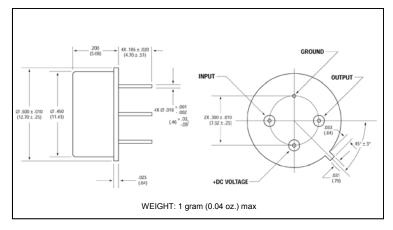
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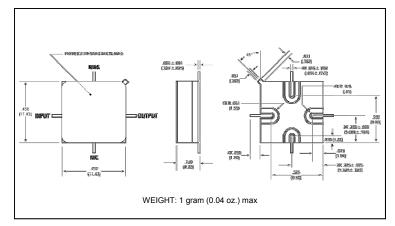
Typical Performance Curves at +25°C

Gain 10.0 S 9.8 100 400 700 1000 1300 1600 FREQUENCY - MHz Noise Figure FIGURE - dB 5.0 100 700 1000 1300 FREQUENCY - MHz Power Output* 20.0 100 400 700 1000 1300 1600 1900 2200 50 FREQUENCY - MHz * at 1 dB Gain Compression Intercept Point 2ND HARMONIC INTERCEPT POINT 3RD ORDER INTERCEPT POINT 400 700 1000 1300 1600 1900 2200 100 FREQUENCY - MHz **VSWR** 700 1000 1300 1600 1900 2200 FREQUENCY - MHz

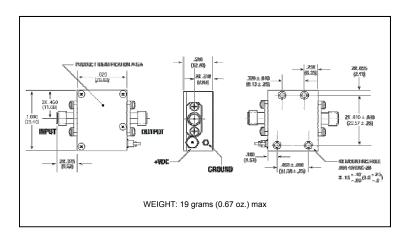
Outline Drawing: TO-8 *



Outline Drawing: Surface Mount



Outline Drawing: SMA Connectorized



* Dimensions are inches (millimeters) ±0.015 (0.38) unless otherwise specified.

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• India Tel: +91.80.4155721 • China Tel: +86.21.2407.1588 Visit www.macomtech.com for additional data sheets and product information.